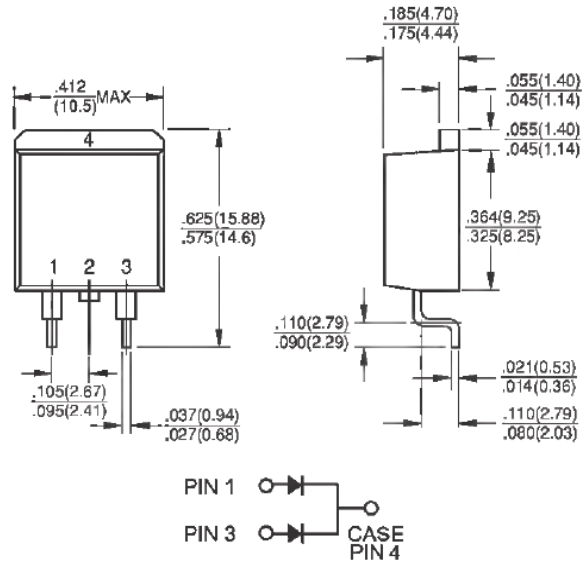




**MBRS10H100CT - MBR10H200CT**  
**10.0AMPS Surface Mount Schottky Barrier Rectifiers**  
**D<sup>2</sup>PAK**

**Features**

- ✧ UL Recognized File # E-326854
- ✧ Plastic material used carriers Underwriters Laboratory Classification 94V-0
- ✧ Metal silicon junction, majority carrier conduction
- ✧ Low power loss, high efficiency
- ✧ High current capability, low forward voltage drop
- ✧ High surge capability
- ✧ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ✧ Guard-ring for overvoltage protection
- ✧ High temperature soldering guaranteed: 260°C/10 seconds/.25", (6.35mm) from case
- ✧ Green compound with suffix "G" on packing code & prefix "G" on datecode



**Mechanical Data**

- ✧ Case: D<sup>2</sup>PAK molded plastic body
- ✧ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ✧ Polarity: As marked
- ✧ Mounting position: Any
- ✧ Mounting torque: 5 in. - lbs, max
- ✧ Weight: 1.41 grams

**Dimensions in inches and (millimeters)**

**Marking Diagram**



- MBR10HXXCT = Specific Device Code  
 G = Green Compound  
 Y = Year  
 WW = Work Week

**Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRS 10H100CT	MBRS 10H150CT	MBRS 10H200CT	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	70	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	100	150	200	V
Maximum Average Forward Rectified Current at $T_C=133^\circ\text{C}$	$I_{F(AV)}$	10			A
Peak Repetitive Surge Current (Rated $V_R$ , Square Wave, 20KHz) at $T_C=133^\circ\text{C}$	$I_{FRM}$	10			A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	120			A
Peak Repetitive Reverse Surge Current (Note 1)	$I_{RRM}$	1		0.5	A
Maximum Instantaneous Forward Voltage (Note 2) $I_F=5A, T_A=25^\circ\text{C}$ $I_F=5A, T_A=125^\circ\text{C}$ $I_F=10A, T_A=25^\circ\text{C}$ $I_F=10A, T_A=125^\circ\text{C}$	$V_F$	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Reverse Current @ Rated $V_R$ $T_A=25^\circ\text{C}$ $T_A=125^\circ\text{C}$	$I_R$	5 1			$\mu\text{A}$ mA
Voltage Rate of Change, (Rated $V_R$ )	$dV/dt$	10000			V/us
Typical Thermal Resistance	$R_{\theta JC}$	3.5			$^\circ\text{C/W}$
Operating Temperature Range	$T_J$	- 65 to + 175			$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	- 65 to + 175			$^\circ\text{C}$

Note 1: 2.0uS Pulse Width, f=1.0KHz

Note 2: Pulse Test : 300uS Pulse Width, 1% Duty Cycle

Note 3: Chip Mounting (on case), where lead does not overlap heatsink with 0.11" offset.

Note 4: Chip Mounting (on case), where leads do overlap heatsink.

Note 5: Screw mounting with 4-40 screw, where washer diameter is  $\leq 4.9\text{mm}$  (0.19")

## RATINGS AND CHARACTERISTIC CURVES (MBRS10H100CT THRU MBRS10H200CT)

FIG. 1 FORWARD CURRENT DERATING CURVE

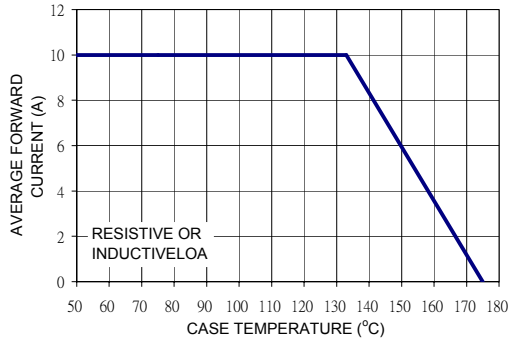


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

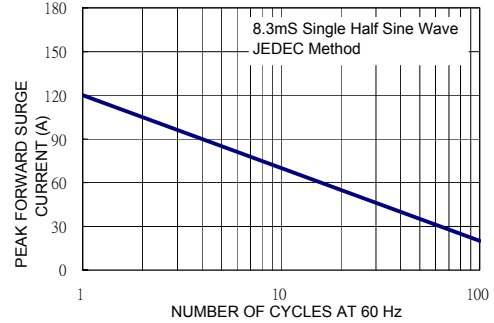


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

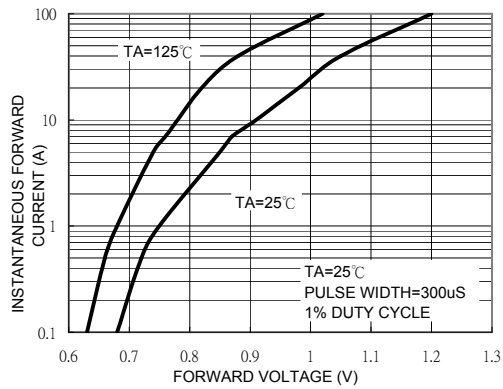


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

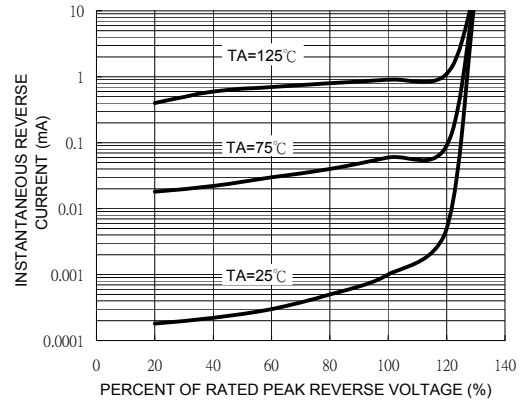


FIG. 5 TYPICAL JUNCTION CAPACITANCE

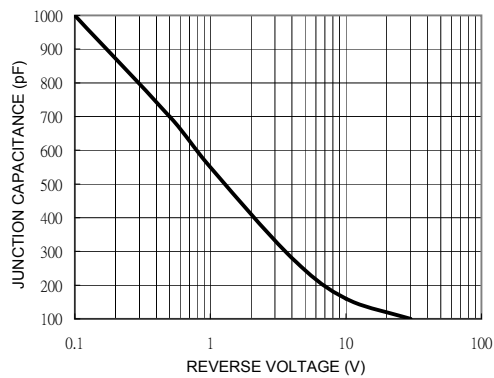


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE

